K	leg. No. :
Quest	ion Paper Code : 50436
Electronic	EXAMINATION, NOVEMBER/DECEMBER 2017 Third Semester and Communication Engineering ELECTRONIC CIRCUITS – I (Regulations 2013)
Time : Three Hours	Maximum: 100 Mark
	vierive the resessory aquations to alcolate the value
	Answer ALL questions
1. What is operating point?	PART – A (10×2=20 Marks)
<ol> <li>What is operating point?</li> <li>What is thermal runaway</li> </ol>	
3. What is bypass and coupli	
<ol> <li>List the need for boot stray</li> <li>What is BiMOS?</li> </ol>	pping in ampliner.
<ul><li>5. What is BiMOS ?</li><li>6. A self biased P-channel JF supply voltage is 12 V. Dete</li></ul>	FET has a pinch off voltage of 5V and $I_{DSS} = 12$ mA. The ermine the values of resistors $R_D$ and $R_D$ , so that $I_D = 5$ mA
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<ol> <li>What is BiMOS ?</li> <li>A self biased P-channel JF supply voltage is 12 V. Dete and V<sub>DS</sub> = 6 V.</li> </ol>	FET has a pinch off voltage of 5V and $I_{DSS}=12$ mA. The ermine the values of resistors $R_D$ and $R_S$ , so that $I_D=5$ mA for ?
<ul> <li>5. What is BiMOS?</li> <li>6. A self biased P-channel JF supply voltage is 12 V. Dete and V<sub>DS</sub> = 6 V.</li> <li>7. What is Miller effect?</li> </ul>	FET has a pinch off voltage of 5V and $I_{DSS}=12$ mA. The ermine the values of resistors $R_D$ and $R_S$ , so that $I_D=5$ mA for ?
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12. a) With a neat diagram explain the small signal analysis of common emitter amplifier and derive the necessary equations to calculate the voltage gain, input and output impedance.

(OR)

- b) With a neat diagram explain the operation of differential amplifier and derive the necessary equations to calculate the CMRR.
- a) With a neat diagram explain the small signal analysis of common source amplifier with a source resistance for MOSFET.

(OR

- b) With a neat diagram explain the source follower amplifier using MOSFET and derive the necessary equations to calculate the voltage gain, input and output resistance.
- 14. a) Explain the high frequency response of common emitter amplifier and derive the necessary equations to calculate the upper 3-dB frequency.

(OR)

- b) Define  $f_{\alpha}$  and  $f_{\beta}$  and  $f_{\tau}$ . Also derive for  $f_{\alpha}$ ,  $f_{\beta}$  and  $f_{\tau}$  with two source terminal and one sink terminal and derive for source and sink terminal currents as a function of reference current.
- 15. a) Explain the basic MOSFET current steering circuit.

(OR)

- Explain and derive for AV for CG NMOS amplifier with following active loads
   Diode connected enhanced PMOS.
  - ii) Depletion PMOS.

PART - C

(1×15=15 Marks)

16. a) Design a differential amplifier using CMOS and calculate the CMRR.

(OR

b) What is cascade amplifier? Explain with necessary equations and explain how to determine its bandwidth.